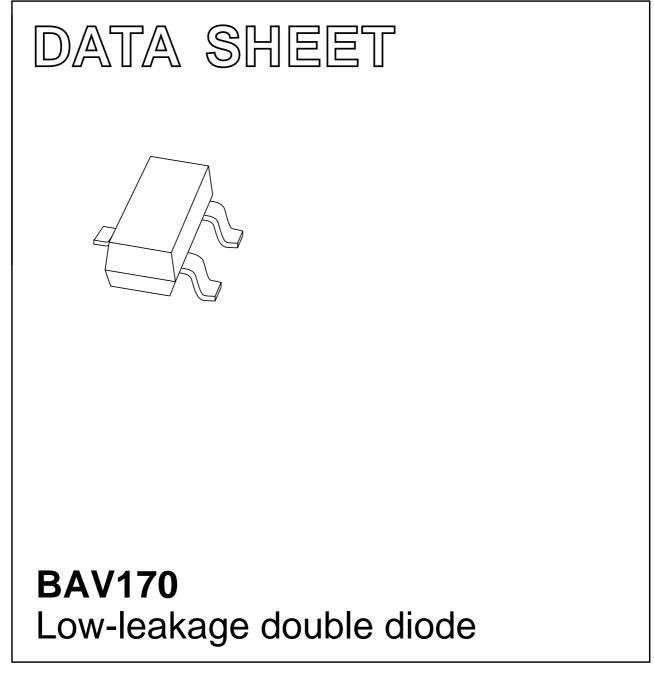
## DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 May 11 2003 Mar 25



2003 Mar 25

**Philips Semiconductors** 

# Low-leakage double diode

### FEATURES

- Plastic SMD package
- Low leakage current: typ. 3 pA
- Switching time: typ. 0.8 μs
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

### APPLICATION

• Low-leakage current applications in surface mounted circuits.

### MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>	
BAV170	JX*	

### Note

- 1. \* = p: Made in Hong Kong.
  - \* = t : Made in Malaysia.
  - \* = W : Made in China.

### DESCRIPTION

Epitaxial, medium-speed switching, double diode in a small SOT23 plastic SMD package. The diodes are in common cathode configuration.

PIN	DESCRIPTION	
1	anode	
2	anode	
3	common cathode	

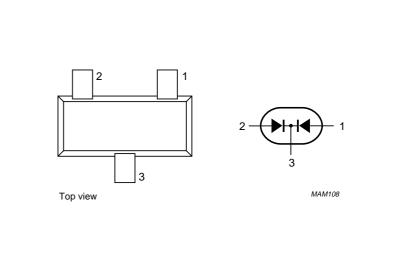


Fig.1 Simplified outline (SOT23) and symbol.

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### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode				ł	·
V <sub>RRM</sub>	repetitive peak reverse voltage		-	85	V
V <sub>R</sub>	continuous reverse voltage		-	75	V
I <sub>F</sub>	continuous forward current	single diode loaded; note 1; see Fig.2	-	215	mA
		double diode loaded; note 1; see Fig.2	-	125	mA
I <sub>FRM</sub>	repetitive peak forward current		-	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		$t_p = 1 \ \mu s$	-	4	А
		t <sub>p</sub> = 1 ms	-	1	А
		$t_p = 1 s$	-	0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

### Note

1. Device mounted on a FR4 printed-circuit board.

### **ELECTRICAL CHARACTERISTICS**

 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode				-	•
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 1 mA	-	900	mV
		I <sub>F</sub> = 10 mA	_	1000	mV
		I <sub>F</sub> = 50 mA	_	1100	mV
		I <sub>F</sub> = 150 mA	-	1250	mV
I <sub>R</sub>	reverse current	see Fig.5			
		V <sub>R</sub> = 75 V	0.003	5	nA
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	3	80	nA
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$		_	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	0.8	3	μs

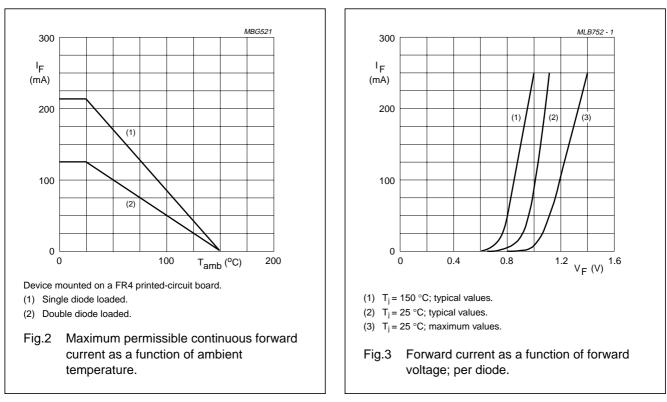
#### THERMAL CHARACTERISTICS

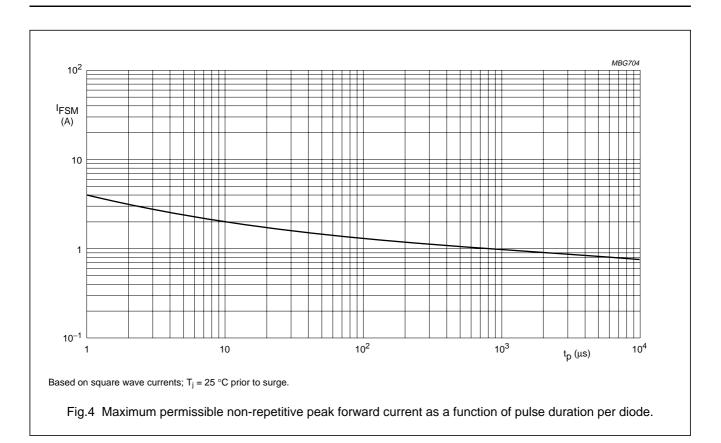
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point		360	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

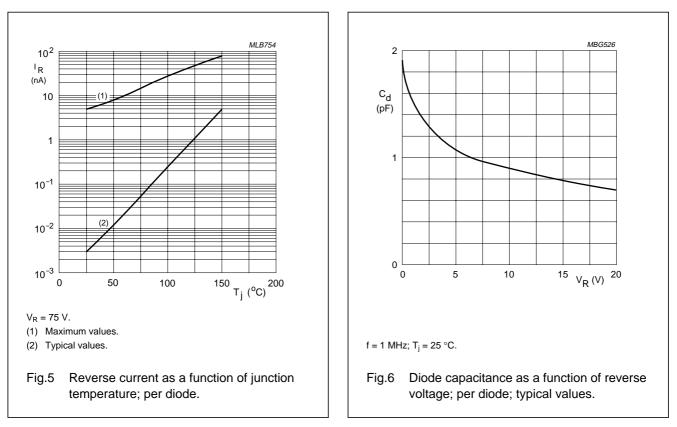
#### Note

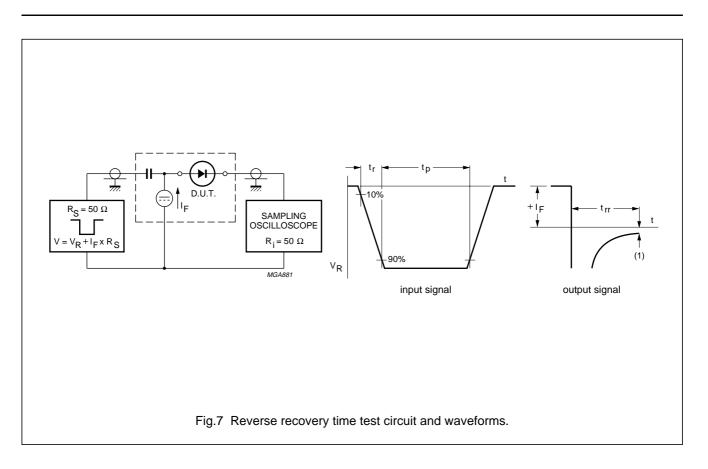
1. Device mounted on a FR4 printed-circuit board.

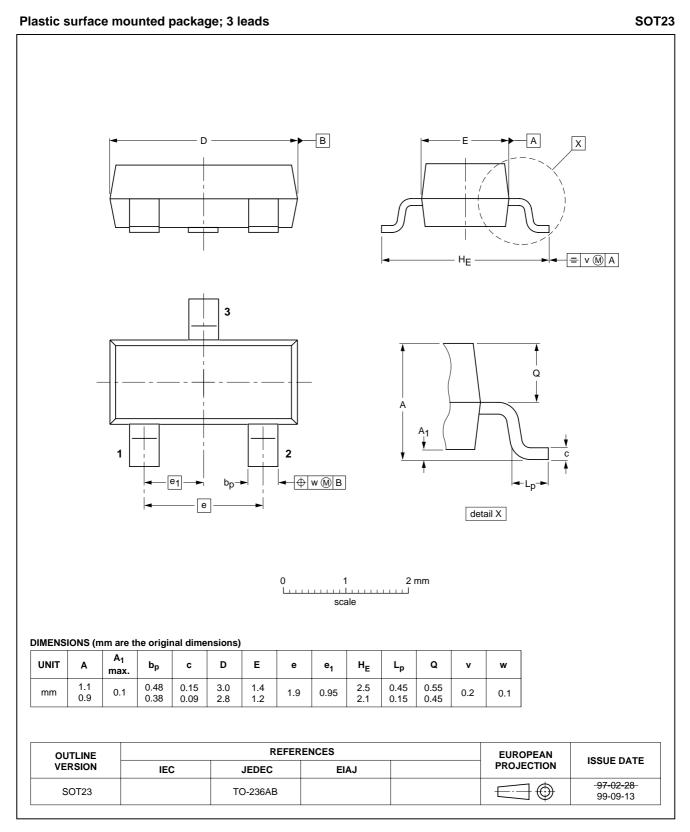
#### **GRAPHICAL DATA**











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### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

#### Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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